

**INFORMATION DISCLOSURE  
STATEMENT**

Atty Docket:  
Serial No.: 59684  
Applicant: CHAI ET AL.  
Filing Date: May 3, 2001  
Group:


**U.S. PATENT DOCUMENTS**

Examiner Initials		Document Number	Date	Name	Class	Sub Class	Filing Date
MM	AA	6,163,099	12/19/00	Kadota et al.	310	313A	
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						

**FOREIGN PATENT DOCUMENTS**

		Document Number	Date	Country	Class	Sub Class	Translation
	AL						

**OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)**

MM	AM	Chai et al., 1999 Joint Meeting EFTF-IEEE ICFS, <i>Growth of High Quality Single Domain Crystals of Langasite Family Compounds</i> , Crystal Photonics, Inc., pages 821-828
	AN	Mill et al., 1999 Joint Meeting EFTF-IEEE ICFS, <i>Synthesis, Growth and some Properties of Single Crystals with the Ca<sub>2</sub>Ga<sub>2</sub>Ge<sub>4</sub>O<sub>14</sub> Structure</i> , Moscow State University, pages 829-834
	AO	Takeda et al., <i>Synthesis and Characterization of Sr<sub>3</sub>TaGa<sub>3</sub>Si<sub>2</sub>O<sub>14</sub> Single Crystals</i> , Materials Research Bulletin 35 (2000), pages 245-252
	AP	Chai et al., <i>A New Class of Ordered Langasite Structure Compounds</i> , Crystal Photonics, Inc., CREOL, University of Central Florida, 2000, pages 163-168
	AQ	
	AR	

EXAMINER:

DATE CONSIDERED:

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.